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FAIRCHILD

SEMICONDUCTOR

FQP50N06 60V N-Channel MOSFET

General Description

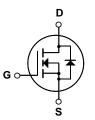
These N-Channel enhancement mode power field effect transistors are produced using Fairchild's proprietary, planar stripe, DMOS technology.

This advanced technology has been especially tailored to minimize on-state resistance, provide superior switching performance, and withstand high energy pulse in the avalanche and commutation mode. These devices are well suited for low voltage applications such as automotive, DC/ DC converters, and high efficiency switching for power management in portable and battery operated products.

Features

- 50A, 60V, $R_{DS(on)}$ = 0.022 Ω @V_{GS} = 10 V Low gate charge (typical 31 nC)
- Low Crss (typical 65 pF)
- Fast switching
- 100% avalanche tested
- Improved dv/dt capability
- 175°C maximum junction temperature rating





Absolute Maximum Ratings T_C = 25°C unless otherwise noted

Symbol	Parameter		FQP50N06	Units
V _{DSS}	Drain-Source Voltage		60	V
I _D	Drain Current - Continuous (T _C = 25°	C)	50	А
	- Continuous (T _C = 100°C)		35.4	A
I _{DM}	Drain Current - Pulsed	(Note 1)	200	A
V _{GSS}	Gate-Source Voltage		± 25	V
E _{AS}	Single Pulsed Avalanche Energy	(Note 2)	490	mJ
I _{AR}	Avalanche Current	(Note 1)	50	A
E _{AR}	Repetitive Avalanche Energy	(Note 1)	12	mJ
dv/dt	Peak Diode Recovery dv/dt (Note 3)		7.0	V/ns
PD	Power Dissipation (T _C = 25°C)		120	W
	- Derate above 25°C		0.8	W/°C
T _J , T _{STG}	Operating and Storage Temperature Range		-55 to +175	°C
TL	Maximum lead temperature for soldering purposes,		300	°C
· L	1/8" from case for 5 seconds		000	

Thermal Characteristics

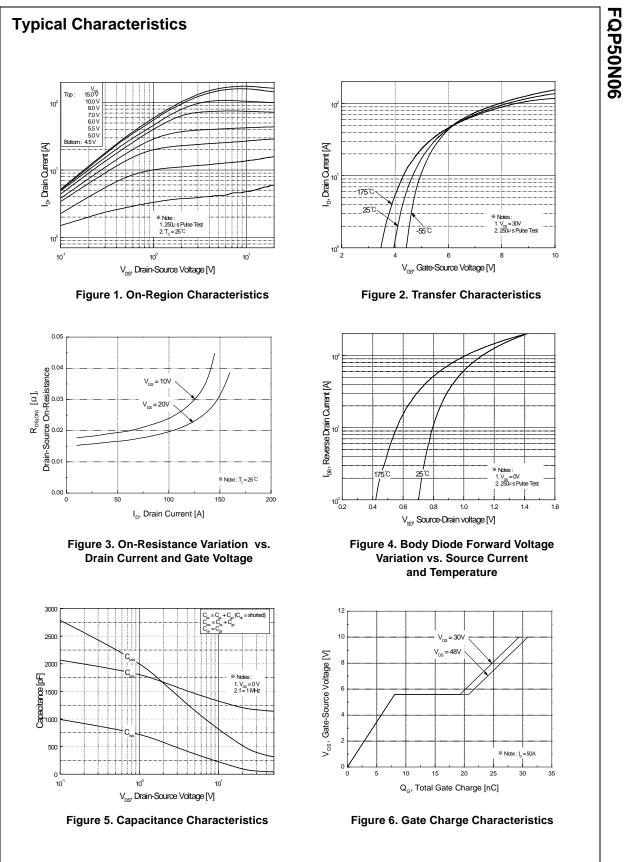
Symbol	Parameter	Тур	Max	Units
$R_{\theta JC}$	Thermal Resistance, Junction-to-Case		1.24	°C/W
$R_{\theta CS}$	Thermal Resistance, Case-to-Sink	0.5		°C/W
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient		62.5	°C/W

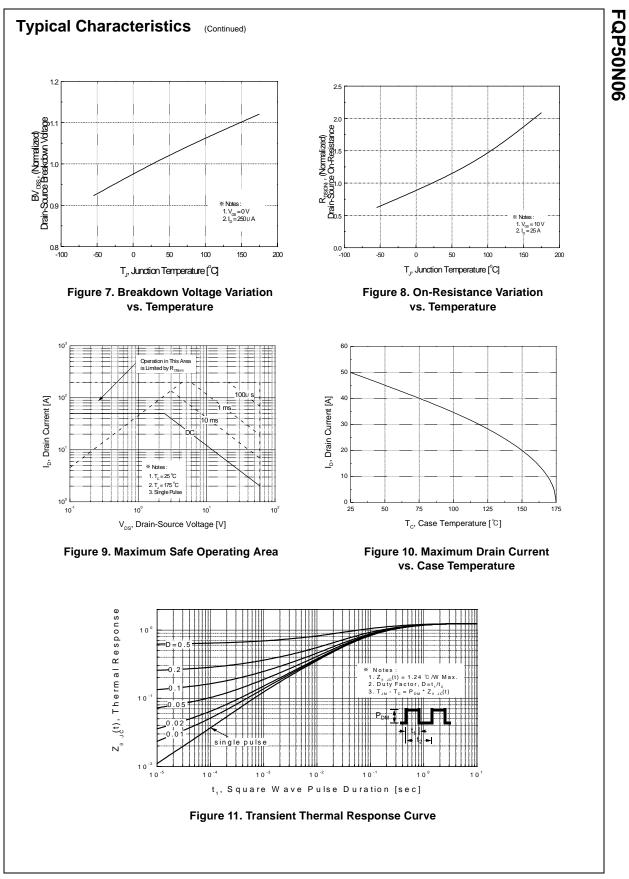
QFET™

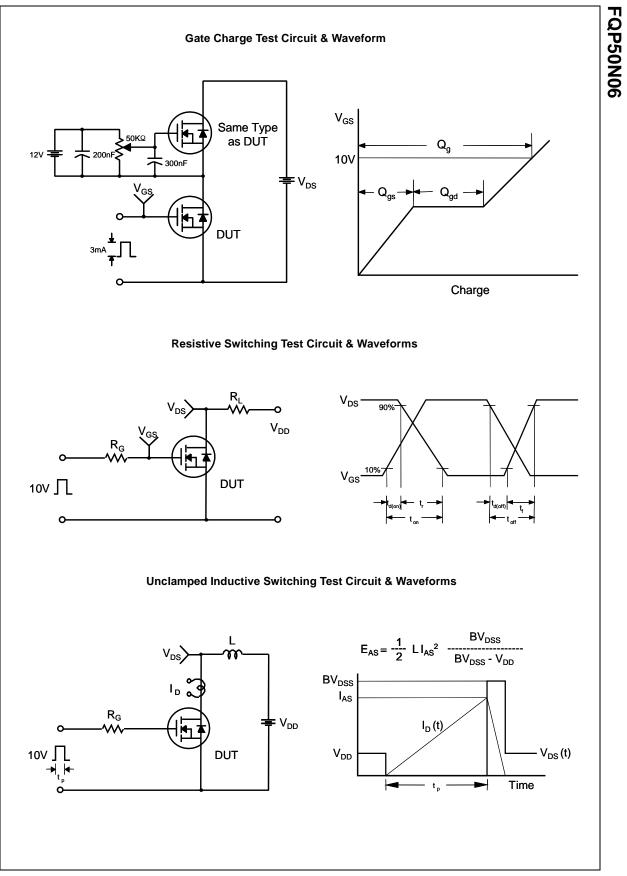
Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Off Cha	aracteristics					
BV _{DSS}	Drain-Source Breakdown Voltage	$V_{GS} = 0 V, I_{D} = 250 \mu A$	60			V
ΔBV _{DSS} / ΔT _J	Breakdown Voltage Temperature Coefficient	$I_D = 250 \ \mu\text{A}$, Referenced to 25°C		0.06		V/°C
IDSS	Zero Gate Voltage Drain Current	V _{DS} = 60 V, V _{GS} = 0 V			1	μA
		V _{DS} = 48 V, T _C = 150°C			10	μA
I _{GSSF}	Gate-Body Leakage Current, Forward	V _{GS} = 25 V, V _{DS} = 0 V			100	nA
I _{GSSR}	Gate-Body Leakage Current, Reverse	$V_{GS} = -25 \text{ V}, \text{ V}_{DS} = 0 \text{ V}$			-100	nA
On Cha	aracteristics		1	I	1	
V _{GS(th)}	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	2.0		4.0	V
R _{DS(on)}	Static Drain-Source On-Resistance	$V_{GS} = 10 \text{ V}, \text{ I}_{D} = 25 \text{ A}$		0.018	0.022	Ω
9 _{FS}	Forward Transconductance	V _{DS} = 25 V, I _D = 25 A (Note 4)		22		S
C _{oss} C _{rss}	Output Capacitance Reverse Transfer Capacitance	V _{DS} = 25 V, V _{GS} = 0 V, f = 1.0 MHz		440 65	580 90	pF pF
C _{rss}	Reverse Transfer Capacitance			65	90	pF
Switchi	ing Characteristics	T		r	1	
t _{d(on)}	Turn-On Delay Time	V _{DD} = 30 V, I _D = 25 A,		15	40	ns
t _r	Turn-On Rise Time	$R_{G} = 25 \Omega$		105	220	ns
t _{d(off)}	Turn-Off Delay Time			60	130	ns
t _f	Turn-Off Fall Time	(Note 4, 5)		65	140	ns
Qg	Total Gate Charge	$V_{DS} = 48 \text{ V}, \text{ I}_{D} = 50 \text{ A},$		31	41	nC
Q _{gs}	Gate-Source Charge	V _{GS} = 10 V		8		nC
Q _{gd}	Gate-Drain Charge	(Note 4, 5)		13		nC
Drain-S	Source Diode Characteristics a	nd Maximum Ratings	1	L	1	
I _S	Maximum Continuous Drain-Source Did	ode Forward Current			50	А
I _{SM}	Maximum Pulsed Drain-Source Diode F	iode Forward Current			200	А
	Drain-Source Diode Forward Voltage	$V_{GS} = 0 V, I_{S} = 50 A$			1.5	V
V _{SD}			1	50		
v _{SD} t _{rr}	Reverse Recovery Time	$V_{GS} = 0 V, I_{S} = 50 A,$		52		ns

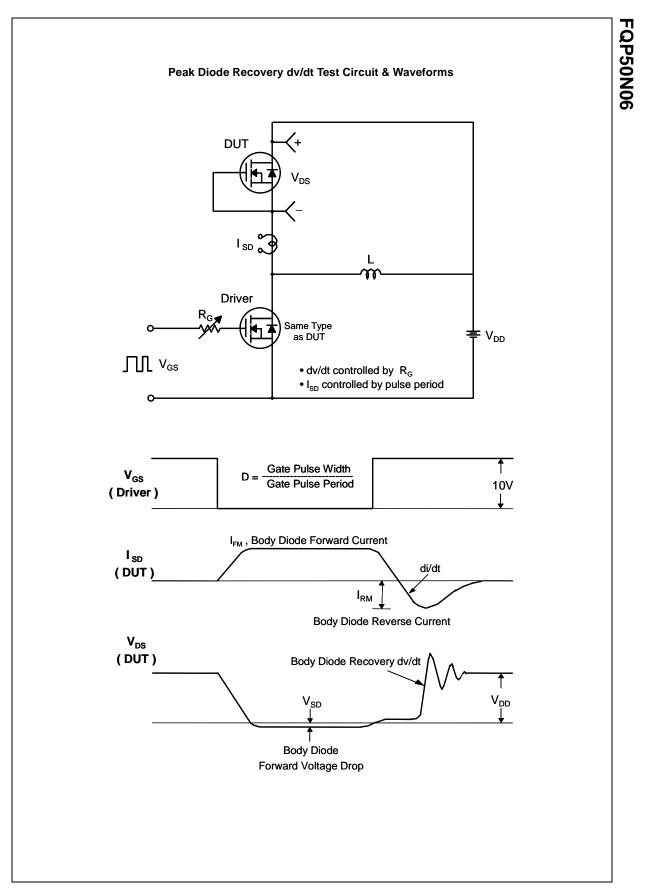
Notes: 1. Repetitive Rating : Pulse width limited by maximum junction temperature 2. L = 230µH, I_{AS} = 50A, V_{DD} = 25V, R_{G} = 25 Ω , Starting T_{J} = 25°C 3. $I_{SD} \le 50A$, di/dt $\le 300A/\mu_{S}$, $V_{DD} \le BV_{DSS}$, Starting T_{J} = 25°C 4. Pulse Test : Pulse width $\le 300\mu_{S}$, Duty cycle $\le 2\%$ 5. Essentially independent of operating temperature

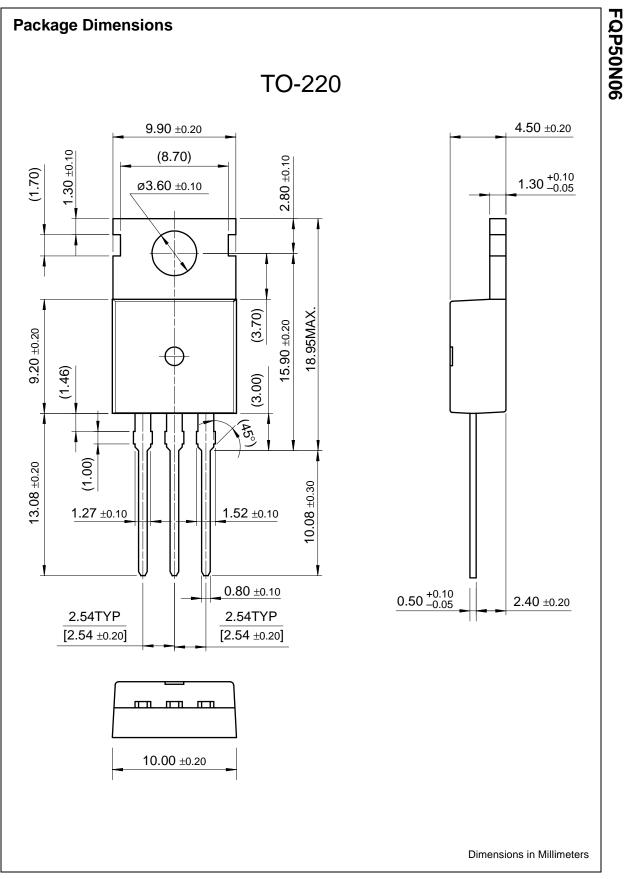
FQP50N06











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